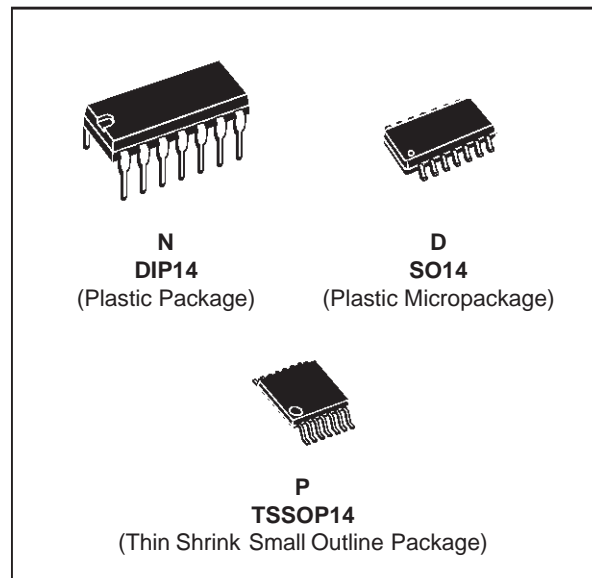




TS924

RAIL TO RAIL HIGH OUTPUT CURRENT QUAD OPERATIONAL AMPLIFIER

- RAIL TO RAIL INPUT AND OUTPUT
- LOW NOISE : $9\text{nV}/\sqrt{\text{Hz}}$
- LOW DISTORTION
- HIGH OUTPUT CURRENT : **80mA**
(able to drive 32Ω loads)
- HIGH SPEED : **4MHz** $1.3\text{V}/\mu\text{s}$
- OPERATING FROM **2.7V to 12V**
- LOW INPUT OFFSET VOLTAGE :
900 μV max. (TS924A)
- ESD INTERNAL PROTECTION : 2KV
- LATCH-UP IMMUNITY
- MACROMODEL INCLUDED IN THIS SPECIFICATION



DESCRIPTION

The TS924 is a RAIL TO RAIL quad BiCMOS operational amplifier optimized and fully specified for 3V and 5V operation.

High output current allows low load impedances to be driven.

The TS924 exhibits a very low noise, low distortion, low offset and high output current capability making this device an excellent choice for high quality, low voltage or battery operated audio systems.

The device is stable for capacitive loads up to 500pF.

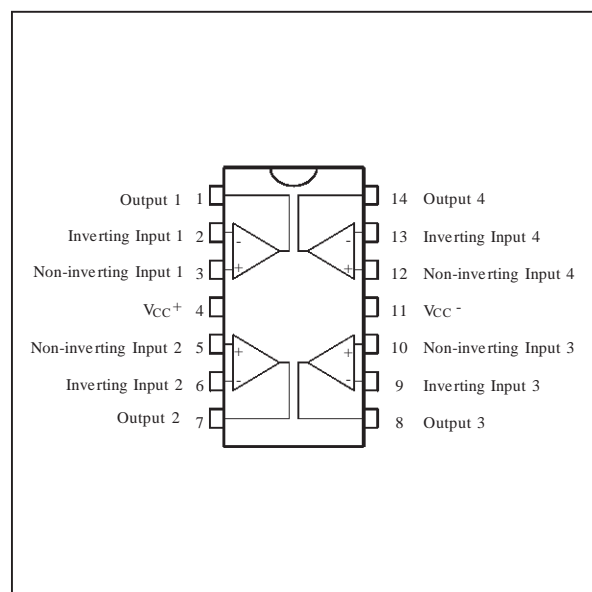
APPLICATIONS

- headphone amplifier
- piezoelectric speaker driver
- sound cards
- MPEG boards, multimedia systems, ...
- line driver, buffer
- cordless telephones and portable communication equipment
- instrumentation with low noise as key factor

ORDER CODES

Part Number	Temperature Range	Package		
		N	D	P
TS924I	-40, +125°C	•	•	•

PIN CONNECTIONS (top view)



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage - (note 1)	14	V
V_{id}	Differential Input Voltage - (note 2)	± 1	V
V_i	Input Voltage - (note 3)	-0.3 to 14	V
T_{oper}	Operating Free Air Temperature Range	-40 to +125	$^{\circ}C$
T_j	Maximum Junction Temperature	150	$^{\circ}C$
R_{thja}	Thermal Resistance Junction to Ambient	130	$^{\circ}C/W$
	Output Short Circuit Duration	see note 4	

Notes :

1. All voltage values, except differential voltage are with respect to network ground terminal.
2. Differential voltages are the non-inverting input terminal with respect to the inverting input terminal.
3. The magnitude of input and output voltages must never exceed $V_{CC}^{+} + 0.3V$.
4. Short-circuits can cause excessive heating. Destructive dissipation can result from simultaneous short-circuit on all amplifiers.

OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	2.7 to 12	V
V_{icm}	Common Mode Input Voltage Range	$V_{DD}^{-} - 0.2$ to $V_{CC}^{+} + 0.2$	V

ELECTRICAL CHARACTERISTICS
 $V_{CC}^+ = 3V$, $T_{amb} = 25^{\circ}C$ (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Unit
V_{io}	Input Offset Voltage $T_{min.} \leq T_{amb} \leq T_{max.}$			3 0.9 5 1.8	mV
DV_{io}	Input Offset Voltage Drift		2		$\mu V/^{\circ}C$
I_{io}	Input Offset Current $V_{out} = 1.5V$		1	30	nA
I_{ib}	Input Bias Current $V_{out} = 1.5V$		15	100	nA
V_{OH}	High Level Output Voltage R_L connected to $V_{CC}/2$	2.90 2.87	2.63		V
V_{OL}	Low Level Output Voltage R_L connected to $V_{CC}/2$		180	50 100	mV
A_{vd}	Large Signal Voltage Gain ($V_{out} = 2V_{pk-pk}$)		200 35 16		V/mV
I_{CC}	Total Supply Current no load, $V_{out} = V_{CC}/2$		4.5	7	mA
GBP	Gain Bandwidth Product $R_L = 600\Omega$		4		MHz
CMR	Common Mode Rejection Ratio	60	80		dB
SVR	Supply Voltage Rejection Ratio $V_{CC} = 2.7$ to $3.3V$	60	85		dB
I_o	Output Short Circuit Current	50	80		mA
SR	Slew Rate	0.7	1.3		V/ μs
ϕ_m	Phase Margin at Unity Gain $R_L = 600\Omega, C_L = 100pF$		68		Degrees
G_m	Gain Margin $R_L = 600\Omega, C_L = 100pF$		12		dB
e_n	Equivalent Input Noise Voltage $f = 1kHz$		9		$\frac{nV}{\sqrt{Hz}}$
THD	Total Harmonic Distortion $V_{out} = 2V_{pk-pk}, F = 1kHz, A_V = 1, R_L = 600\Omega$		0.005		%
C_s	Channel Separation		120		dB

ELECTRICAL CHARACTERISTICS

$V_{CC}^+ = 5V$, $T_{amb} = 25^{\circ}C$ (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Unit
V_{io}	Input Offset Voltage $T_{min.} \leq T_{amb} \leq T_{max.}$			3 0.9 5 1.8	mV
DV_{io}	Input Offset Voltage Drift		2		$\mu V/^{\circ}C$
I_{io}	Input Offset Current $V_{out} = 1.5V$		1	30	nA
I_{ib}	Input Bias Current $V_{out} = 1.5V$		15	100	nA
V_{OH}	High Level Output Voltage R_L connected to $V_{CC}/2$	$R_L = 100k$ 4.90 $R_L = 600\Omega$ 4.85 $R_L = 32\Omega$	4.4		V
V_{OL}	Low Level Output Voltage R_L connected to $V_{CC}/2$	$R_L = 10k$ $R_L = 600\Omega$ $R_L = 32\Omega$	300	50 120	mV
A_{vd}	Large Signal Voltage Gain ($V_{out} = 2V_{pk-pk}$)	$R_L = 10k$ $R_L = 600\Omega$ $R_L = 32\Omega$	200 40 17		V/mV
I_{CC}	Total Supply Current no load, $V_{out} = V_{CC}/2$		4.5	7	mA
GBP	Gain Bandwidth Product $R_L = 600\Omega$		4		MHz
CMR	Common Mode Rejection Ratio	60	80		dB
SVR	Supply Voltage Rejection Ratio $V_{CC} = 3V$ to $5V$	60	85		dB
I_o	Output Short Circuit Current	50	80		mA
SR	Slew Rate	0.7	1.3		V/ μs
ϕ_m	Phase Margin at Unity Gain $R_L = 600\Omega, C_L = 100pF$		68		Degrees
G_m	Gain Margin $R_L = 600\Omega, C_L = 100pF$		12		dB
e_n	Equivalent Input Noise Voltage $f = 1kHz$		9		$\frac{nV}{\sqrt{Hz}}$
THD	Total Harmonic Distortion $V_{out} = 2V_{pk-pk}, F = 1kHz, A_V = 1, R_L = 600\Omega$		0.005		%
C_s	Channel Separation		120		dB

MACROMODEL

- RAIL TO RAIL INPUT AND OUTPUT
- LOW NOISE : **9nV/√Hz**
- LOW DISTORTION

- HIGH OUTPUT CURRENT : **80mA**
(able to drive **32Ω** loads)
- HIGH SPEED : **4MHz, 1.3V/μs**
- OPERATING FROM **2.7V TO 12V**

** Standard Linear Ics Macromodels, 1996.

** CONNECTIONS :

- * 1 INVERTING INPUT
- * 2 NON-INVERTING INPUT
- * 3 OUTPUT
- * 4 POSITIVE POWER SUPPLY
- * 5 NEGATIVE POWER SUPPLY

R2P 19 4 1E+07

R2N 19 5 1E+07

VINT1 500 0 5

GCONVP 500 501 119 4 19.38 !envoie ds VP,
I(VP)=(V119-V4)/2/Ut VP 501 0 0

GCONVN 500 502 119 5 19.38 !envoie ds VN,
I(VN)=(V119-V5)/2/Ut VN 502 0 0

***** orientation isink isource *****

VINT2 503 0 5

FCOPY 503 504 VOUT 1

DCOPYP 504 505 MDTH 400E-9

VCOPYP 505 0 0

DCOPYN 506 504 MDTH 400E-9

VCOPYN 0 506 0

F2PP 19 5 poly(2) VCOPYP VP 0 0 0 0 0.5 !multiplie
I(vout)*I(VP)=lout*(V119-V4)/2/Ut

F2PN 19 5 poly(2) VCOPYP VN 0 0 0 0 0.5
!multiplie I(vout)*I(VN)=lout*(V119-V5)/2/Ut

F2NP 19 5 poly(2) VCOPYN VP 0 0 0 0 1.75
!multiplie I(vout)*I(VP)=lout*(V119-V4)/2/Ut

F2NN 19 5 poly(2) VCOPYN VN 0 0 0 0 1.75
!multiplie I(vout)*I(VN)=lout*(V119-V5)/2/Ut

* COMPENSATION *****

CC 19 119 25p

* OUTPUT*****

DOPM 19 22 MDTH 400E-12

DONM 21 19 MDTH 400E-12

HOPM 22 28 VOUT 6.250000E+02

VIPM 28 4 5.000000E+01

HONM 21 27 VOUT 6.250000E+02

VINM 5 27 5.000000E+01

VOUT 3 23 0

ROUT 23 19 6

COUT 3 5 1.300000E-10

DOP 19 25 MDTH 400E-12

VOP 4 25 1.052

DON 24 19 MDTH 400E-12

VON 24 5 1.052

.ENDS

.SUBCKT TS924 1 3 2 4 5 (analog)

.MODEL MDTH D IS=1E-8 KF=2.664234E-16
CJO=10F

* INPUT STAGE

CIP 2 5 1.000000E-12

CIN 1 5 1.000000E-12

EIP 10 5 2 5 1

EIN 16 5 1 5 1

RIP 10 11 8.125000E+00

RIN 15 16 8.125000E+00

RIS 11 15 2.238465E+02

DIP 11 12 MDTH 400E-12

DIN 15 14 MDTH 400E-12

VOFP 12 13 DC 153.5u

VOFN 13 14 DC 0

IPOL 13 5 3.200000E-05

CPS 11 15 1e-9

DINN 17 13 MDTH 400E-12

VIN 17 5 -0.100000e+00

DINR 15 18 MDTH 400E-12

VIP 4 18 0.400000E+00

FCP 4 5 VOFP 1.865000E+02

FCN 5 4 VOFN 1.865000E+02

FIBP 2 5 VOFP 6.250000E-03

FIBN 5 1 VOFN 6.250000E-03

* GM1 STAGE *****

FGM1P 119 5 VOFP 1.1

FGM1N 119 5 VOFN 1.1

RAP 119 4 2.6E+06

RAN 119 5 2.6E+06

* GM2 STAGE *****

G2P 19 5 119 5 1.92E-02

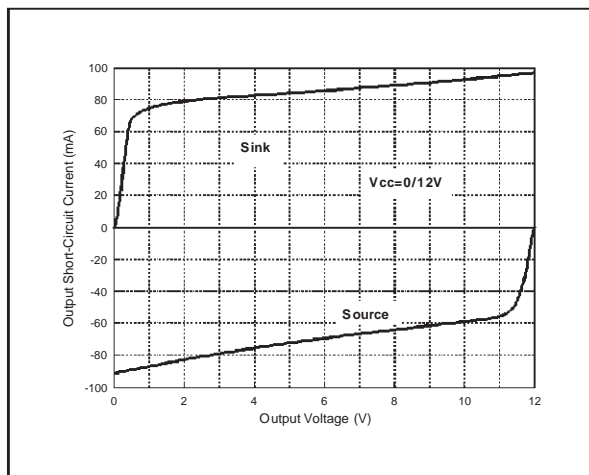
G2N 19 5 119 4 1.92E-02

ELECTRICAL CHARACTERISTICS

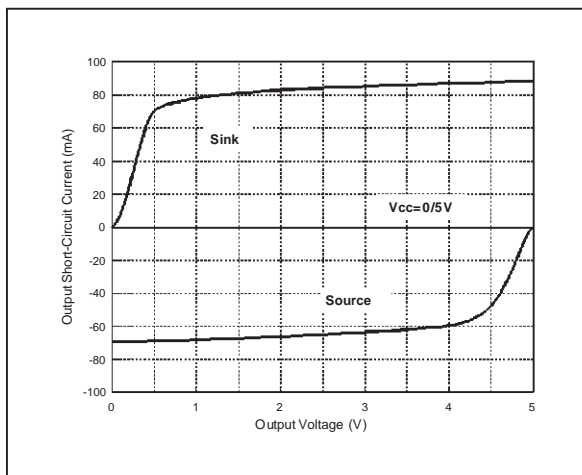
$V_{CC}^+ = 3V$, $V_{CC}^- = 0V$, R_L, C_L connected to $V_{CC}/2$, $T_{amb} = 25^\circ C$
(unless otherwise specified)

Symbol	Conditions	Value	Unit
V_{io}		0	mV
A_{vd}	$R_L = 10k\Omega$	200	V/mV
I_{CC}	No load, per operator	1.2	mA
V_{icm}		-0.2 to 3.2	V
V_{OH}	$R_L = 10k\Omega$	2.95	V
V_{OL}	$R_L = 10k\Omega$	25	mV
I_{sink}	$V_O = 3V$	80	mA
I_{source}	$V_O = 0V$	80	mA
GBP	$R_L = 600\Omega$	4	MHz
SR	$R_L = 10k\Omega, C_L = 100pF$	1	V/ μs
θ_m	$R_L = 600\Omega$	68	Degrees

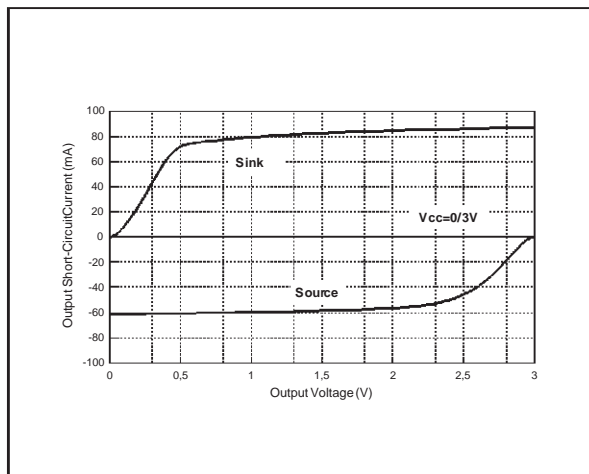
OUTPUT SHORT CIRCUIT CURRENT vs OUTPUT VOLTAGE



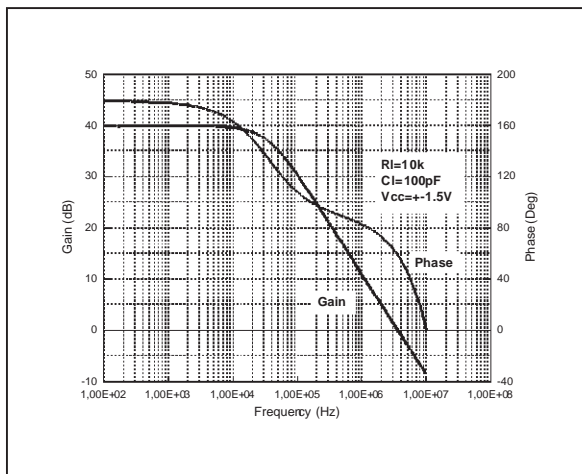
OUTPUT SHORT CIRCUIT CURRENT vs OUTPUT VOLTAGE



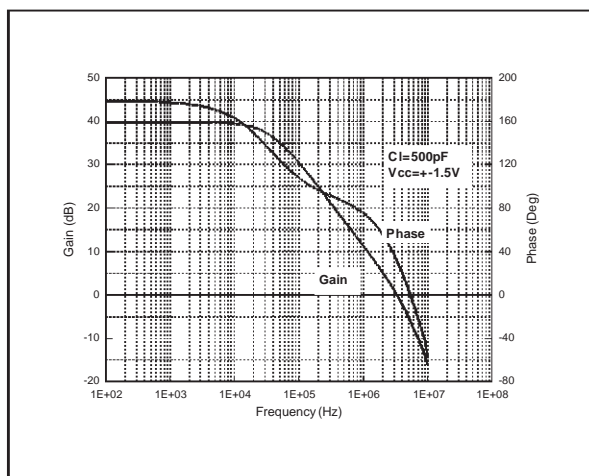
OUTPUT SHORT CIRCUIT CURRENT vs OUTPUT VOLTAGE



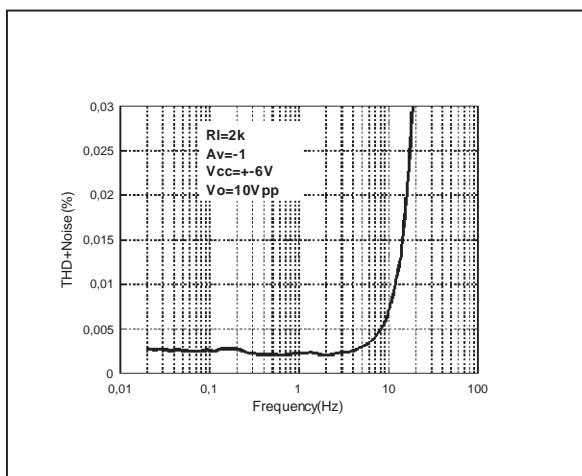
VOLTAGE GAIN AND PHASE vs FREQUENCY



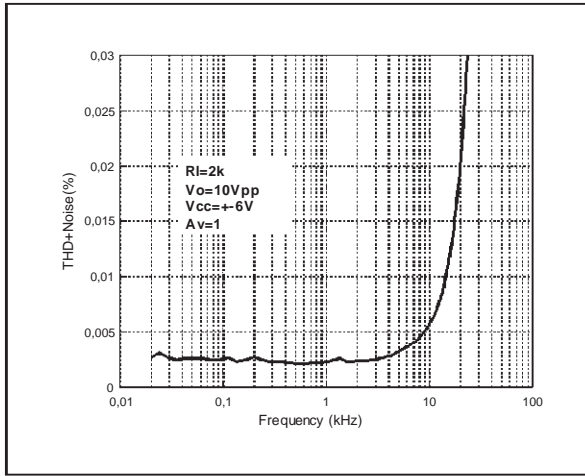
VOLTAGE GAIN AND PHASE vs FREQUENCY



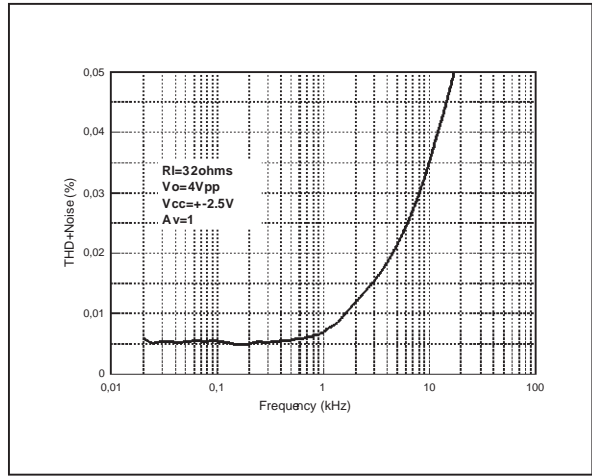
THD + NOISE vs FREQUENCY



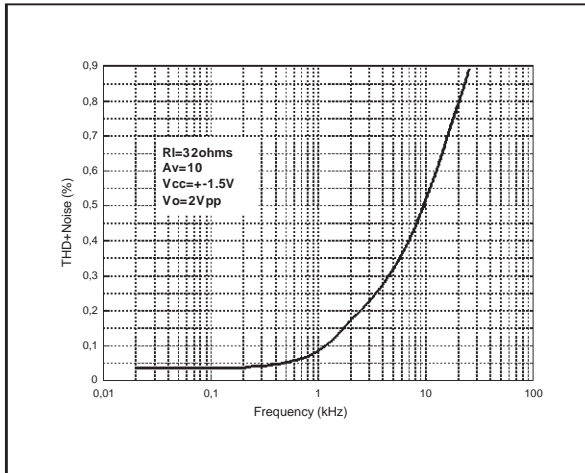
THD + NOISE vs FREQUENCY



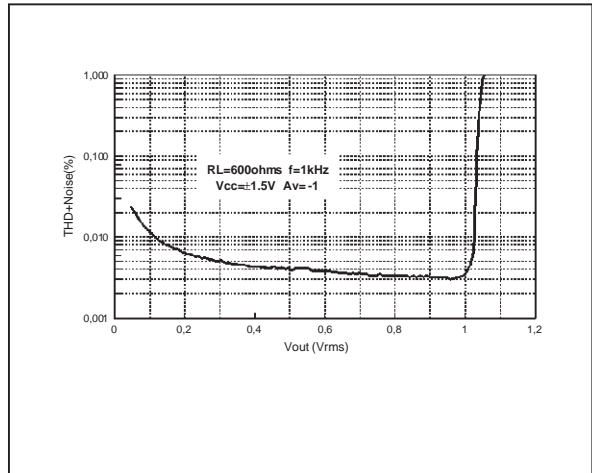
THD + NOISE vs FREQUENCY



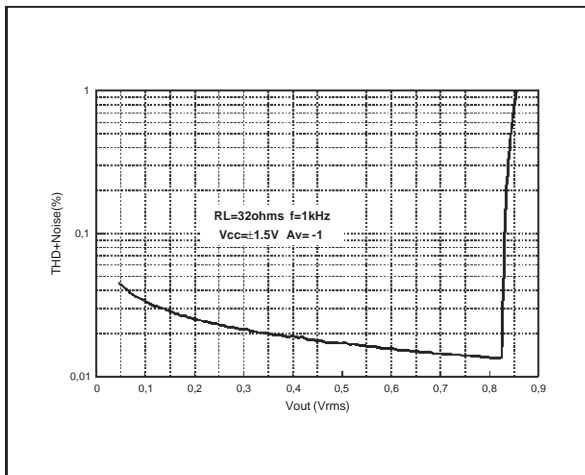
THD + NOISE vs FREQUENCY



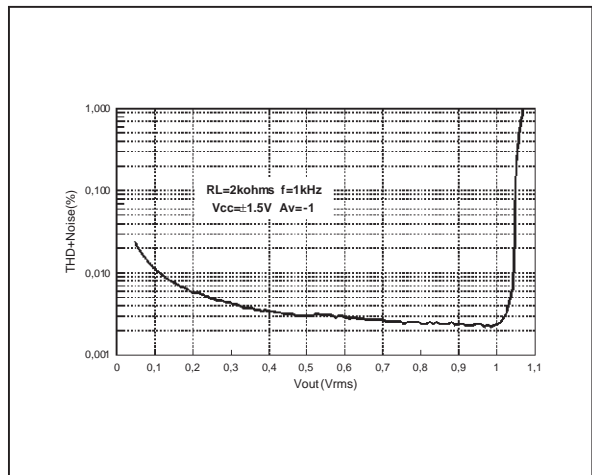
THD + NOISE vs V_{OUT}



THD + NOISE vs V_{OUT}

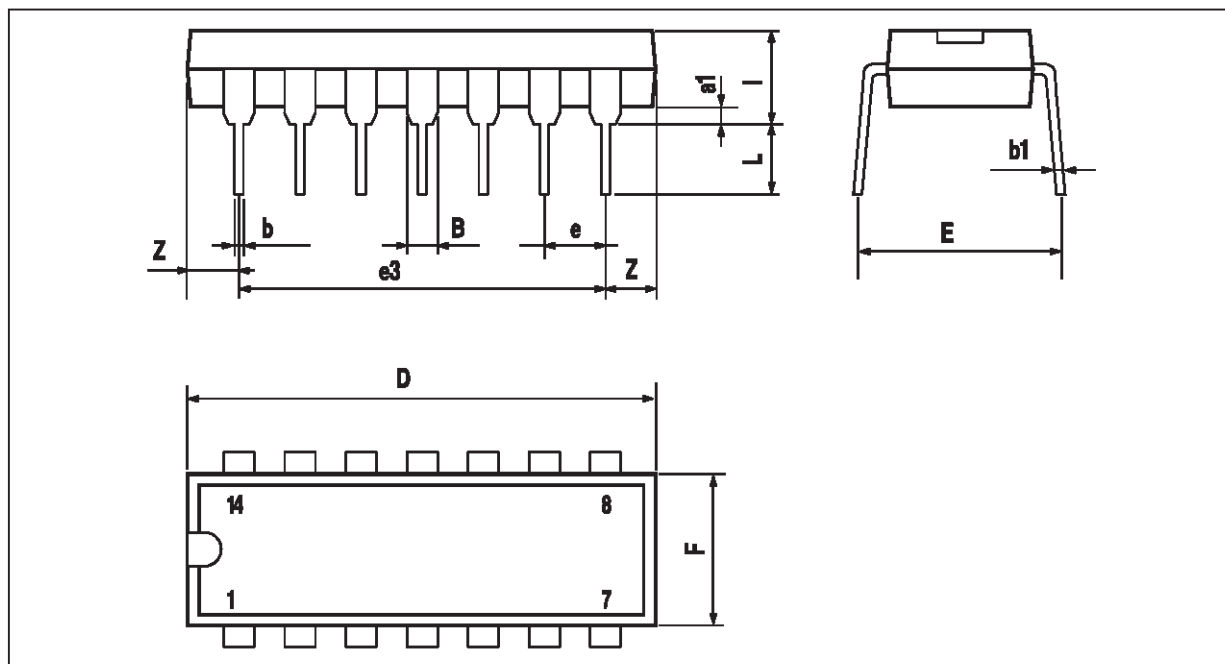


THD + NOISE vs V_{OUT}



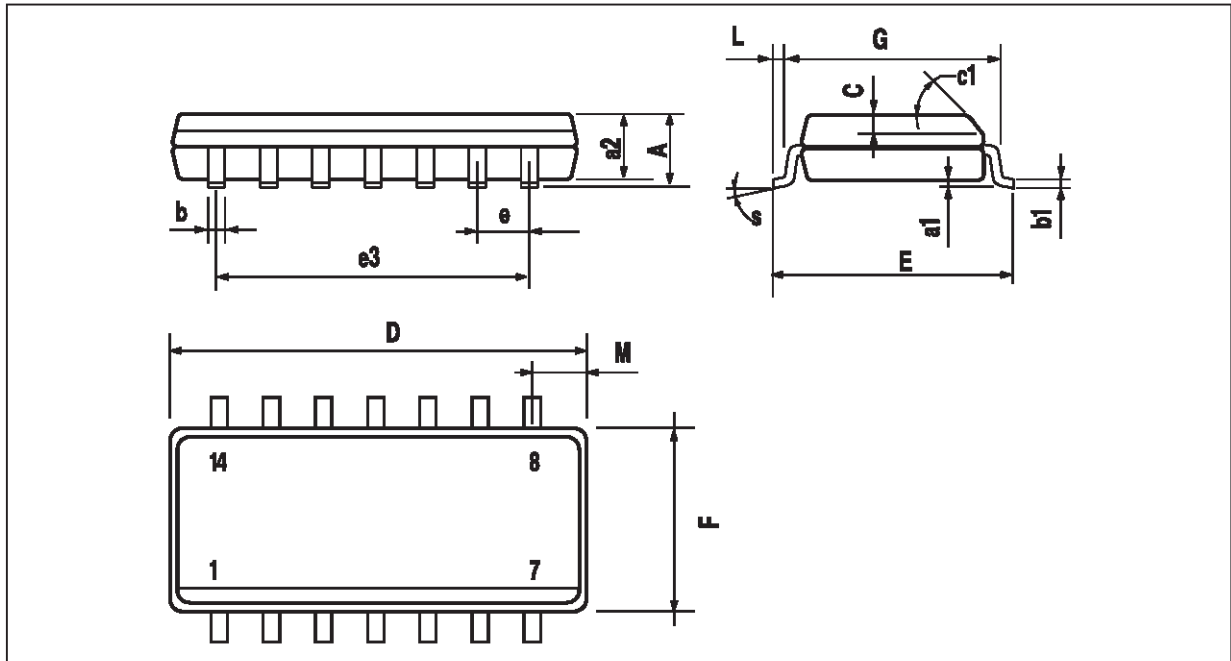
PACKAGE MECHANICAL DATA

14 PINS - PLASTIC DIP

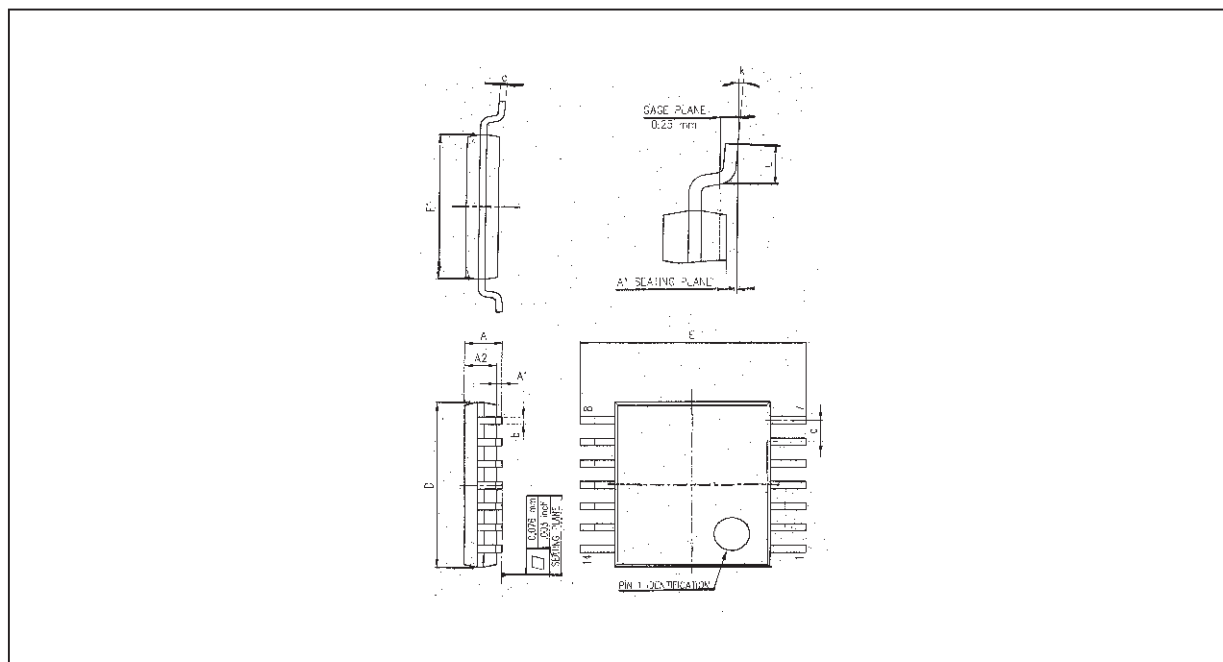


Dim.	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
a1	0.51			0.020		
B	1.39		1.65	0.055		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
e		2.54			0.100	
e3		15.24			0.600	
F			7.1			0.280
i			5.1			0.201
L		3.3			0.130	
Z	1.27		2.54	0.050		0.100

PACKAGE MECHANICAL DATA
 14 PINS - PLASTIC MICROPACKAGE (SO)



Dim.	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.75			0.069
a1	0.1		0.2	0.004		0.008
a2			1.6			0.063
b	0.35		0.46	0.014		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.020	
c1	45° (typ.)					
D	8.55		8.75	0.336		0.334
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		7.62			0.300	
F	3.8		4.0	0.150		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.020		0.050
M			0.68			0.027
S	8° (max.)					

PACKAGE MECHANICAL DATA**14 PINS - THIN SHRINK SMALL OUTLINE PACKAGE**

Dim.	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.20			0.05
A1	0.05		0.15	0.01		0.006
A2	0.80	1.00	1.05	0.031	0.039	0.041
b	0.19		0.30	0.007		0.15
c	0.09		0.20	0.003		0.012
D	4.90	5.00	5.10	0.192	0.196	0.20
E		6.40			0.252	
E1	4.30	4.40	4.50	0.169	0.173	0.177
e		0.65			0.025	
k	0°		8°	0°		8°
l	0.50	0.60	0.75	0.09	0.0236	0.030

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